UNA0216 (UN216)

Transistor array to drive the small motor

Features

- Small and lightweight
- Low power consumption (low V_{CE(sat)} transistor used)
- Low-voltage drive
- With 6 elements incorporated. (SO-14)

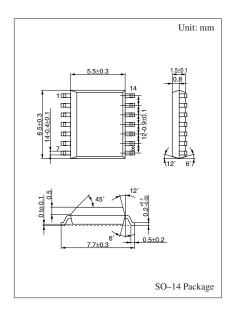
Applications

- Video cameras
- Cameras
- Portable CD players
- Small motor drive circuits in general for electronic equipment.

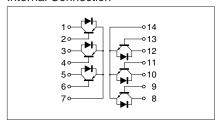
Absolute Maximum Ratings (Ta=25±2°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	±12	V
Collector to emitter voltage	V _{CEO}	±10	V
Emitter to base voltage	V _{EBO}	±7	V
Collector current	I_C	±3	A
Total power dissipation	P_T^*	0.5	W
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Note: \pm marks used above: +: NPN part, -: PNP part



Internal Connection



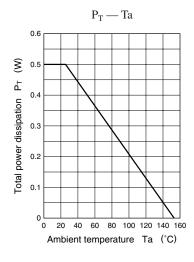
^{*} $T_C = 25$ °C only when the elements are active

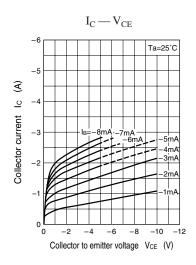
■ Electrical Characteristics (Ta=25±2°C)

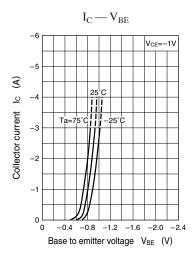
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector cutoff current	I_{CBO}	$(NPN) V_{CB} = 10V$			1	μА	
		$(PNP) V_{CB} = -10V$			-1		
Collector to base voltage	V_{CBO}	(NPN) $I_C = 10\mu A$	12			V	
		(PNP) $I_C = -10\mu A$	-12				
Collector to emitter voltage	V _{CEO}	(NPN) $I_C = 1 \text{mA}$	10			V	
		(PNP) $I_C = -1 \text{mA}$	-10				
Emitter to base voltage	V_{EBO}	(NPN) $I_E = 10\mu A$	7			V	
		(PNP) $I_E = -10\mu A$	-7				
Forward current transfer ratio	h _{FE}	(NPN) $V_{CE} = 1V, I_C = 0.5A*$	200		800		
		(PNP) $V_{CE} = -1V, I_{C} = -0.5A*$	200		800		
Collector to emitter saturation voltage	V _{CE(sat)1}	(NPN) $I_C = 2A$, $I_B = 50mA$			0.25	V	
		(PNP) $I_C = -2A, I_B = -50mA$			- 0.45		
Transition frequency	f_T	(NPN) $V_{CB} = 6V$, $I_E = -50$ mA, $f = 200$ MHz		150		MHz	
		(PNP) $V_{CB} = -6V$, $I_E = 50 \text{mA}$, $f = 200 \text{MHz}$		150		WITZ	
Collector output capacitance	C _{ob}	(NPN) $V_{CB} = 10V, I_{E} = 0, f = 1MHz$		50		pF	
		(PNP) $V_{CB} = 10V, I_{E} = 0, f = 1MHz$		65			
Forward voltage (DC)	V_{F}	(NPN) $I_F = 1A$			1.5	V	
		(PNP) $I_F = -1A$			1.5		

^{*}Pulse measurement

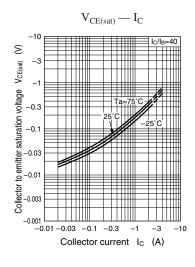
Characteristics charts of PNP transistor block

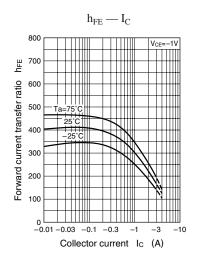


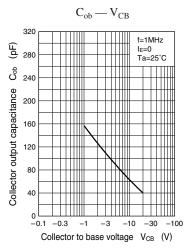




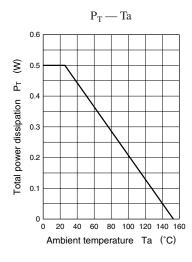
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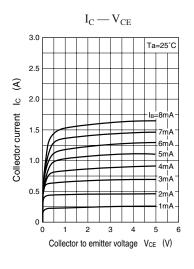


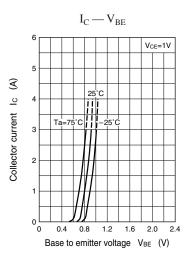


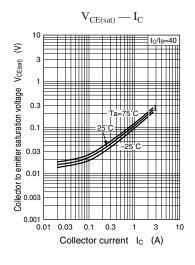


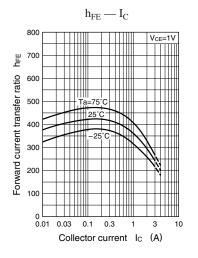
Characteristics charts of NPN transistor block

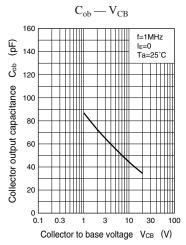












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